Monolithic Digital IC



LB1817W

FDD Spindle Motor Driver

Overview

The LB1817W is a spindle motor driver for low-profile floppy disk drives.

Functions and Features

- Three-phase full-wave linear drive (with external PNP transistor)
- Low saturation voltage
- Built-in digital speed control
- Start/stop circuit (Low active)
- Switchable rotation speed
- Current limiter circuit
- Built-in index processing circuit
- Index timing adjustable by VR
- AGC circuit
- Thermal protection circuit

Package Dimensions

unit: mm

3163A-SQFP48



Specifications

Absolute Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max		7.0	V
Maximum output current	I _{CC} max1	t ≤ 0.5s	1.5	А
Maximum constant output current	I _O max2		1.0	А
Allowable power dissipation	Pd max1	IC only	0.45	W
Operating temperature	Topr		-20 to +80	°C
Storage temperature	Tstg		-40 to +150	°C

Allowable Operating Ranges at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Power supply voltage	V _{CC}		4.2 to 6.5	V

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Electrical Characteristics at Ta = 25°C, V_{CC} = 5V

Parameter	Symbol	Conditions		Ratings		Unit
			min	typ	max	•
Current drain	Icco	S/S = 5V (Standby)		70	100	μΑ
	I _{CC}	S/S = 0V (Normal)		25	35	mA
MS1 bias current	I _{MS} 1	$V_{MS}1 = 5V$		180	270	μΑ
MS1 Low input voltage	V _{MS} 1L		0.0		0.8	V
MS1 High input voltage	V _{MS} 1H		2		V _{CC}	V
MS2 bias current	I _{MS} 2	$V_{MS}2 = 5V$		90	135	μA
MS2 Low input voltage	V _{MS} 2L		0.0		0.8	V
MS2 High input voltage	V _{MS} 2H		2		V _{CC}	V
MS3 bias current	I _{MS} 3	$V_{MS}3 = 5V$		90	135	μΑ
MS3 Low input voltage	V _{MS} 3L		0.0		0.8	V
MS3 High input voltage	V _{MS} 3H		2		V _{CC}	V
S/S bias current	I _{S/S}				20	μA
S/S Low voltage	V _{S/SL}		0.0		0.8	V
S/S High voltage	V _{S/SH}		2		V _{CC}	V
Hall amplifier input bias current	I _{HB}				15	μA
Common mode input voltage range	Vh		2.0		V _{CC} -0.7	V
Differential input voltage range	Vdif		50		200	mVp-p
Input offset voltage	Vho	*			±10	mV
Hall bias output voltage	V _H	I _H = 5 mA	0.5	0.8	1.1	V
		S/S = 5V	0.5	0.0	±10	
Leakage current	V _{HL}			0.45	0.64	μA V
Output saturation voltage	V(sat)	I _O = 0.8A		0.45		
Output leakage current	I _{OL}				1	mA
Current limiter	lim	$R_F = 3 k\Omega, R_{OUT} = 100\Omega$	6.3	7.5	8.7	mA
Control amplifier voltage gain	G _C		-7.5	-5.5	-3.5	dB
Voltage gain phase differential	ΔG_{C}				±1	dB
V/I conversion source current	I +		19	28	37	μΑ
V/I conversion sink current	-		-19	-28	-37	μA
V/I conversion current ratio	+/ -		0.8	1.0	1.2	
DSC buffer input current	IDSC				1	μΑ
FG amplifier input voltage	V _{FG}	f _{FG} = 300 Hz	2		20	mVp-p
FG amplifier voltage gain	G _{FG}	Open loop*		60		dB
FG amplifier input offset	V _{FGO}	*			±10	mV
FG amplifier internal reference voltage	V _{FGB}		2.2	2.5	2.8	V
FG Schmitt hysteresis width	∆Vsh1	High -> Low*		25		mV
-	∆Vsh2	Low -> High*		25		mV
Speed discriminator count	Ν	<u>_</u>		1390/2		
Discriminator operating frequency	F _D	*			1.1	MHz
Oscillator frequency	F _{OSC}	*			1.1	MHz
Oscillator frequency tolerance	ΔF _{OSC}				±0.2	%
Index output Low voltage	V	I _O = 2 mA			0.4	70 V
Index output leakage current	V _{IDL}				±10	
	I _{IDL}		0.0			μΑ V
Index amplifier common mode input voltage range	VI		0.2		V _{CC} -0.7	
ndex amplifier differential input voltage range	V _{DIF}	Hysteresis width < 25 mA	25	1.0	100	mV
Index amplifier hysteresis set current	I _{HYS}		2.9	4.2	5.5	μΑ
Timing adjustment at High level	V _{TH}	MS1 = L	1.15	1.26	1.35	V
Timing adjustment at Low level	V _{TL}	MS1 = L	0.40	0.52	0.60	V
Timing adjustment ratio	T _{HL}	V_{TH} (MS1 = L) / V_{TH} (MS1 = H)		1.148		
Reference voltage	V _{REF} 1		2.20	2.50	2.80	V
	V _{REF} 2		1.85	2.15	2.45	V
Thermal protection operating temperature	TSD	*	150	180		°C
Hysteresis width	ΔTSD	*		10		°C

Note: Items shown to be "*" are not measured.

Pin Assignment



Block Diagram



Pin Descriptions

Pin Descr	-			
Pin number	Pin name	Pin voltage	Equivalent circuit	Pin function
1, 5 12, 13 14, 19 24, 25 31, 36 37, 47 48	NC			Pins not used
2	V _{REF} 1	2.5V typ	0 Vcc 100Ω 100Ω 100Ω 100Ω 100Ω 100Ω	 V_{REF}1 pin. Used as power supply for external CR serving for index timing adjustment.
3	V _{REF} 2	2.15V typ	○ V _{CC}	 V_{REF}2 pin. Used as bias pin for external index sensor.
4	I/D		O Vcc	Index pulse output pin.
6	SG			• Signal ground pin. Connect to ground together with pin 21.
7	MS3	H: 2.0V min L: 0.8V max	Ο Vcc 7 \$ 50kΩ 7 \$ 50kΩ	 FG switching pin. High: FG set to through Low: FG set to 1-stage division
8	MS2	H: 2.0V min L: 0.8V max	Ο Vcc	 CLK switching pin. High: Clock set to through Low: Clock set to 1-stage division

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Pin number	Pin name	Pin voltage	Equivalent circuit	Pin function
9	MS1	H: 2.0V min L: 0.8V max	9 \$50kΩ \$5	 Rotation speed switching pin. High: 360 rpm Low: 300 rpm For details, see rotation speed switching table.
10	S/S	H: 2.0V min L: 0.8V max	Ο Vcc 200Ω 10 7/7 7/7 10	 Start/stop switching pin. Low: active
11 15	- +			 External index – input pin. External index + input pin. When I⁻ pin is High, constant current I1 flows. When pin is Low, constant current I1 is cut off. Resistor externally connected to I⁻ pin determines hysteresis width.
16	X1		400Ω 400Ω 400Ω 400Ω 200Ω 16 200Ω 7/7 7/7	Reference clock generator pin.
17	X2		Ο Vcc	
18	FC			 Frequency characteristics compensation pin. To prevent current control loop oscillation, insert a capacitor between this pin and V_{CC}.

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Pin number	Pin name	Pin voltage	Equivalent circuit	Pin function
20	RF			• Output current detection pin. To detect output current as a voltage, insert a resistor R_f between this pin and V_{CC} . The voltage is used for the current limiter. The detection level is about 1/50 of the output current.
21	PG			Output transistor ground pin. Connect to ground together with pin 6.
22 23	FG ⁺ FG ⁻	2.5V typ	22 12kΩ § 12kΩ § 1	 FG amplifier + pin FG amplifier – pin
26	FGout			• FG amplifier output pin.
27 28 29 30 32 33	U _{OUT} U _{PB} V _{OUT} W _{OUT} W _{PB}		$V_{CC} \circ$	 U phase output pin. U phase external PNP transistor base connection. V phase output pin. V phase external PNP transistor base connection. W phase output pin. W phase output pin. W phase external PNP transistor base connection.
34 35 38 39 40 41	U_{IN}^{2} U_{IN}^{1} V_{IN}^{2} V_{IN}^{1} W_{IN}^{2} W_{IN}^{1}		35 200Ω 41 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7	 U phase Hall input pin. Logic High means U_{IN}1 > U_{IN}2. V phase Hall input pin. Logic High means V_{IN}1 > V_{IN}2. W phase Hall input pin. Logic High means W_{IN}1 > W_{IN}2.

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Pin number	Pin name	Pin voltage	Equivalent circuit	Pin function
42	ΗB		Vcc O	 Hall bias negative-side pin. In stop mode, the pin is open and Hall bias is cut off.
43	V _{CC}			 Power supply pin. The voltage supplied to this pin must be stabilized to prevent ripple noise or other noises from inputting to this pin.
44	AGC			 AGC pin. Controls the Hall amplifier gain according to Hall input amplitude. An external capacitor is used.
45	DSC		45 	Speed discriminator pin.
46	СТ			Timing adjustment pin. External CR for time constant circuit is connected here.

Truth Table

	Courses & Sink		Hall input				
	Source -> Sink	U	V	W			
1	V phase -> W phase	Н	Н	L			
2	V phase -> U phase	L	Н	L			
3	W phase -> U phase	L	Н	Н			
4	W phase -> V phase	L	L	Н			
5	U phase -> V phase	Н	L	Н			
6	U phase -> W phase	Н	L	L			

Hall input pin High means $U_{IN}1 > U_{IN}2$ $V_{IN}1 > V_{IN}2$ $W_{IN}1 > W_{IN}2$

Rotation Speed Select Table

foso	_C = 1 MHz	1						
MS1	Н	L	Н	L	Н	L	Н	L
MS2	H		l	_	Н		L	
MS3	ŀ	Н		-	l	-	ŀ	1
f _{FG} [Hz]	720	600	720	600	1440	1200	360	300



Index and Timing Chart



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